

## National Institute of Technology Meghalaya An Institute of National Importance

CURRICULUM

Programme		me	Bachelor of Technology in Electronics and Communication Engineering Year of Regulation										gulation	2018-19				
Department			Electronics and Communication Engineering Semester										ster	V				
Co	urse		Course Name								Credit	Structure			Marks Distribution			
Code			Course mame						L	Т	Р	P C INT		MID	END	END Total		
EC 371			MICROSENSOR TECHNOLOGY						2	0	0	2	50	50	100	2	00	
		To understand the fundamental concepts, working principles and applications of Microsensors								CO1	Understand the fundamental concepts and applications of Microsensors							
	urse ctives	capacit	To design various types of Microsensors based on resistive, capacitive, piezoelectric and thermal transduction mechanisms. To make students understand the fabrication technologies and							Course Outcomes	CO2 CO3	Apply the concept of various transduction mechanisms for the design of MicrosensorsUnderstand the materials and fabrication technologies for						
		materia	Iterials for Microsensors Microsensors.															
No.	COs		Mapping with Program Outcomes (POs)											1			with PSO	
		PO	1 PC	2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	PSO3	PSO
1	CO1	2	2		-	-	-	-	-	-	-	-	-	-	2	1	-	-
2	CO2	2	2		-	-	-	-	-	-	-	-	-	-	2	1	-	-
3	CO3	2	2		-	-	-	-	-	-	-	-	-	-	2	1	-	-
									SYI	LLABUS								
No.	Content													Hours	Hours COs			
II		<b>Transduction mechanisms in Microsensors</b> Piezoresistive, Capacitive, Piezoelectric and Thermal transduction techniques for Microsensors												6		CO2		
III	<b>Technologies and materials for Microsensors</b> Materials used for making Microsensors and their fabrication techniques													6		CO3		
IV	Case studies of selected Microsensors Piezorsisive pressure sensor, Capacitive pressure sensor, Piezoelectric sensor and Temperature sensor													6		CO1, CO2, CO3		
							Total	Hours							24			
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2		•		ions (	of MEM	S", Pearso	on, 2 <sup>nd</sup> Ed	ition, 2012	2.									
Supp		ary Rea	0															
1								Hall India										
	Patr	anabis I	D., "Senso	ors Ai	nd Trans	ducers", P	Prentice-H	[all India,	2 <sup>nd</sup> Ed	. 2004.								
2								use, 2 <sup>nd</sup> Eo										